RESPONSE UNDER 37 C.F.R. § 1.116 EXPEDITED PROCEDURE GROUP ART UNIT 2818

Docket Number 40404.30/tt

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Hiroshi OJI	Art Unit: 2818	
Application No.: 10/572,730	Art Offic. 2018	
Confirmation No.: 6903	Examiner: A. Huynh	
Filing or 371(c) Date: March 21, 2006		
Title: SEMICONDUCTOR DEVICE HAVING HIGH-K GATE DIELECTRIC LAYER AND METHOD FOR MANUFACTURING THE SAME		

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated July 10, 2009, the period for response to which has been extended to November 10, 2009 by the accompanying Petition for a ONE-month Extension of Time, please amend the above-identified application as follows:

Ameno	dments to the Specification begin on page	of this paper.	
🔀 Amend	dments to the Claims are reflected in the lis	sting of the claims which begins or	
page 2 of this pape	er.		
Amend	dments to the Drawings begin on page	of this paper and include an	
attached replacement sheet. An Appendix including the amended drawing figures is attached			
following page	of this paper.		
🔀 Remar	ks/Arguments begin on page 4 of this pape	er.	

Please note, if a box is not checked, then no corresponding amendment is being made.